

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
60V	19mΩ @ V _{GS} = 10V	33.2A
	28mΩ @ V _{GS} = 4.5V	28A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

PowerDI5060-8 (Type C)

- Engine management systems
- Body control electronics
- DC-DC converters

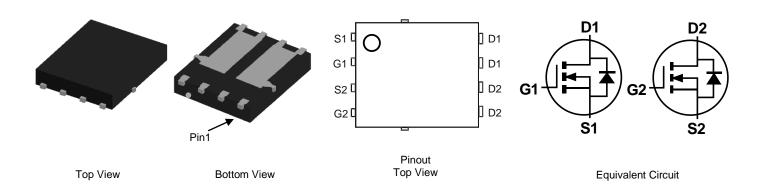
Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6016LPDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Part Number	Backaga	Packing		
	Package	Qty.	Carrier	
DMTH6016LPDQ-13	PowerDI5060-8 (Type C)	2,500	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

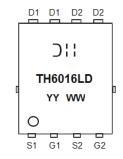
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



);; = Manufacturer's Marking TH6016LD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024) WW = Week (01 to 53)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 6) $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$		ID	33.2 23.7	A
Continuous Drain Current (Note 5) $T_{A} = +25^{\circ}C$ $T_{A} = +100^{\circ}C$		ID	9.2 6.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	ldм	50	А	
Maximum Continuous Body Diode Forward Current (Note 5)	ls	31	А	
Pulsed Body Diode Forward Current (Note 5)	I _{SM}	50	А	
Avalanche Current, L = 0.1mH		I _{AS}	15.3	А
Avalanche Energy, L = 0.1mH		Eas	11.7	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5) T _A = +25°C		PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Roja	58	°C/W	
Total Power Dissipation (Note 6) T _C = +25°C		PD	37.5	W
Thermal Resistance, Junction to Case (Note 6)	Røjc	4	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



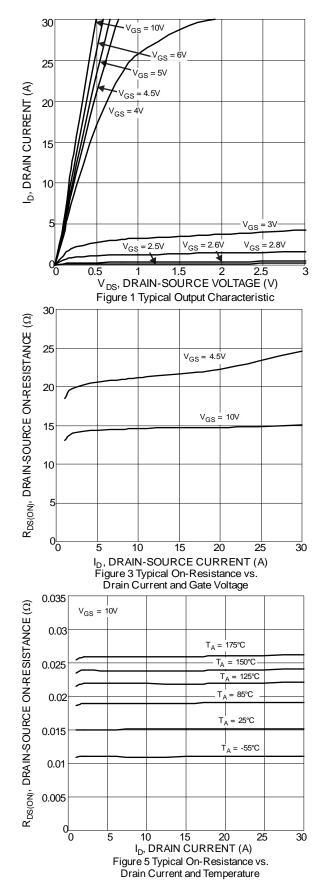
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

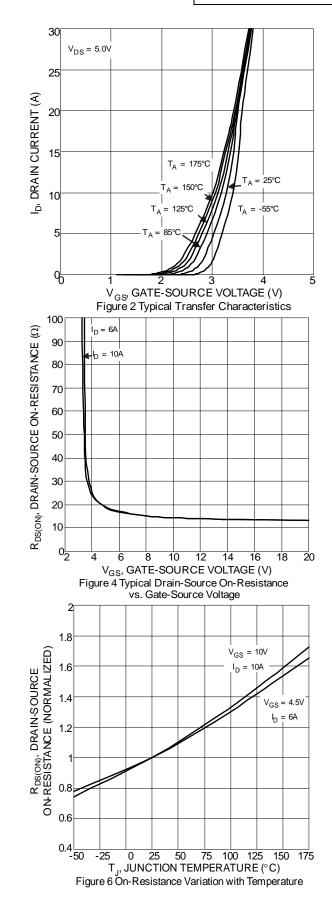
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	V _{DS} = 48V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	1	_	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Proven	_	14.5	19	mΩ	V _{GS} = 10V, I _D = 10A	
Static Drain-Source Of-Resistance	RDS(ON)	—	20.9	28	11152	$V_{GS} = 4.5 V, I_D = 6 A$	
Diode Forward Voltage	Vsd	_	0.7	1.2	V	V _{GS} = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	CISS	—	864	_	pF		
Output Capacitance	Coss	_	282	—	pF	VDS = 30V, VGS = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss	_	27	—	pF		
Gate Resistance	Rg	_	1.3	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q _G		8.4	—	nC		
Total Gate Charge (V _{GS} = 10V)	QG		17	—	nC		
Gate-Source Charge	Qgs		3.1	—	nC	V _{DS} = 30V, I _D = 10A	
Gate-Drain Charge	Qgd		4.3	—	nC	1	
Turn-On Delay Time	t _{D(ON)}	_	3.4	—	ns		
Turn-On Rise Time	tR		5.2	—	ns	$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 10A, R_G = 6\Omega$	
Turn-Off Delay Time	tD(OFF)		13	—	ns		
Turn-Off Fall Time	tF	_	7	—	ns		
Body Diode Reverse Recovery Time	trr	_	22	—	ns		
Body Diode Reverse Recovery Charge	Qrr	_	11	_	nC	—I _F = 10A, di/dt = 100A/μs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



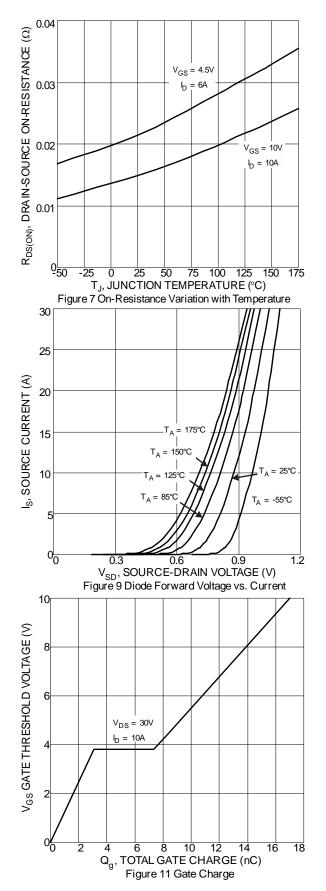
DMTH6016LPDQ

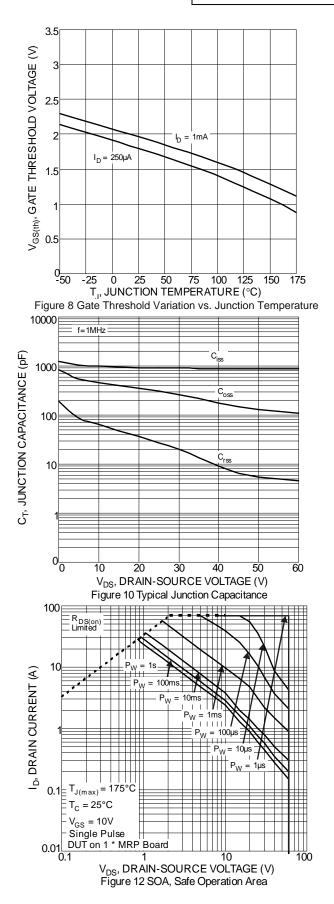




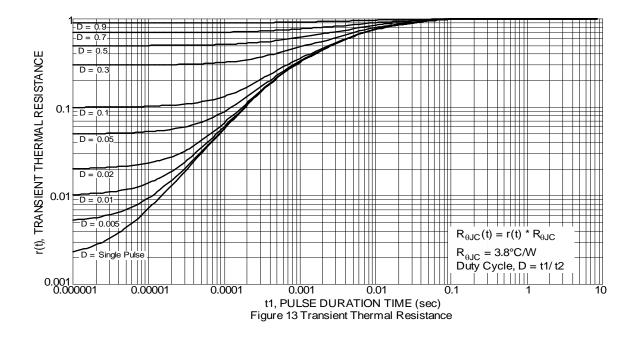
DMTH6016LPDQ Document number: DS39429 Rev. 4 - 2







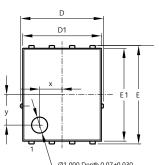






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



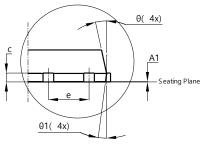
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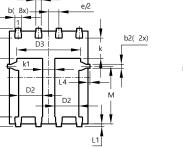


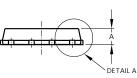




PowerDI5060-8 (Type C)

DETAIL A

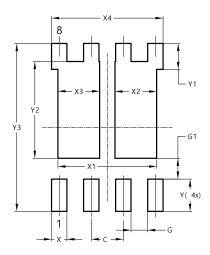




PowerDI5060-8 (Type C)					
Dim	Min	Max	Ту́р		
Α	0.90	1.10	1.00		
A1	0	0.05	0.02		
b	0.33	0.51	0.41		
b1	0.300	0.366	0.333		
b2	0.20	0.35	0.25		
c	0.23	0.33	0.277		
D	5	.15 BS0	0		
D1	4.85	4.95	4.90		
D2	1.40	1.60	1.50		
D3	-	-	3.98		
Е	6	.15 BS0	C		
E1	5.75	5.85	5.80		
E2	3.56	3.76	3.66		
e	1	.27BSC			
k	-	-	1.27		
k1	0.56	-	-		
L	0.51	0.71	0.61		
La	0.51	0.71	0.61		
L1	0.05	0.20	0.175		
L4	-	-	0.125		
М	3.50	3.71	3.605		
х	-	-	1.400		
у	-	-	1.900		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8 (Type C)

Dimensions	Value (in mm)	
С	1.270	
G	0.660	
G1	0.820	
Х	0.610	
X1	3.910	
X2	1.650	
X3	1.650	
X4	4.420	
Y	1.270	
Y1	1.020	
Y2	3.810	
Y3	6.610	

DMTH6016LPDQ Document number: DS39429 Rev. 4 - 2



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